



DESCRIPTION

EST2269 is highly integrated current mode PWM control IC optimized for high performance, low standby power and cost effective offline flyback converter applications in sub 80W range.

PWM switching frequency at normal operation is externally programmable to tight range. At no load or light load condition, the IC operates in extended'burst mode' to minimize switching loss. Lower standby power and higher conversion efficiency in thus achieved.

VDD low startup current and low operating current contribute to a reliable power on startup design with EST2269. A large value resistor could thus be used in the startup circuit to minimize the standby power.

EST2269 offers complete protection coverage with automatic self- recovery feature including Cycle-by-Cycle current limiting (OCP), over temperature protection(OTP),VDD over voltage clamp and under voltage lockout (UVLO). The Gate output is clamped to maximum 18V to protect the power MOSFET.

EST2269 is offered in SOP-8 and DIP-8packages.

FEATURES

- Proprietary frequency shuffling technology for improved EMI performance.
- External programmable PWM switching frequency.
- Leading edge Blanking on current sense input.
- Internal synchronized slope compensation .
- Extended burst mode control for improved efficiency and minimum standby power design
- Low VDD startup current and low operating current.
- Gate output maximum voltage clamp 18V.
- Cycle-by-Cycle Current Limiting, Built-in Adaptive Current Peak Regulation
- Power on Soft-start, Programmable CV and CC Regulation
- VDD Under Voltage Lockout with Hysteresis(UVLO),OVP,OCP,OLP, ClampVDD.
- Buildd-in OTP(120°C, design quaranteed.)

Applications	Ordering Information	
Offline AC/DC flyback converter for ■ Battery Charger ■ Power Adaptor ■ Set-Top Box Power Supplies ■ Open-frame SMPS	Part number	Package
	EST2269S	SOP-8
	EST2269D	DIP-8

Pin Assignments

PD8&SOP8 Package (P-DIP8&SOP8)

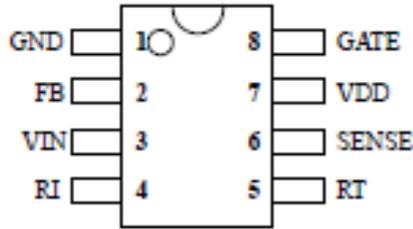


Figure 1. Pin Assignment of EST2269 for P-DIP8&SOP8

Typical Application Circuit

From Bridge Rectifier 127~373v DC

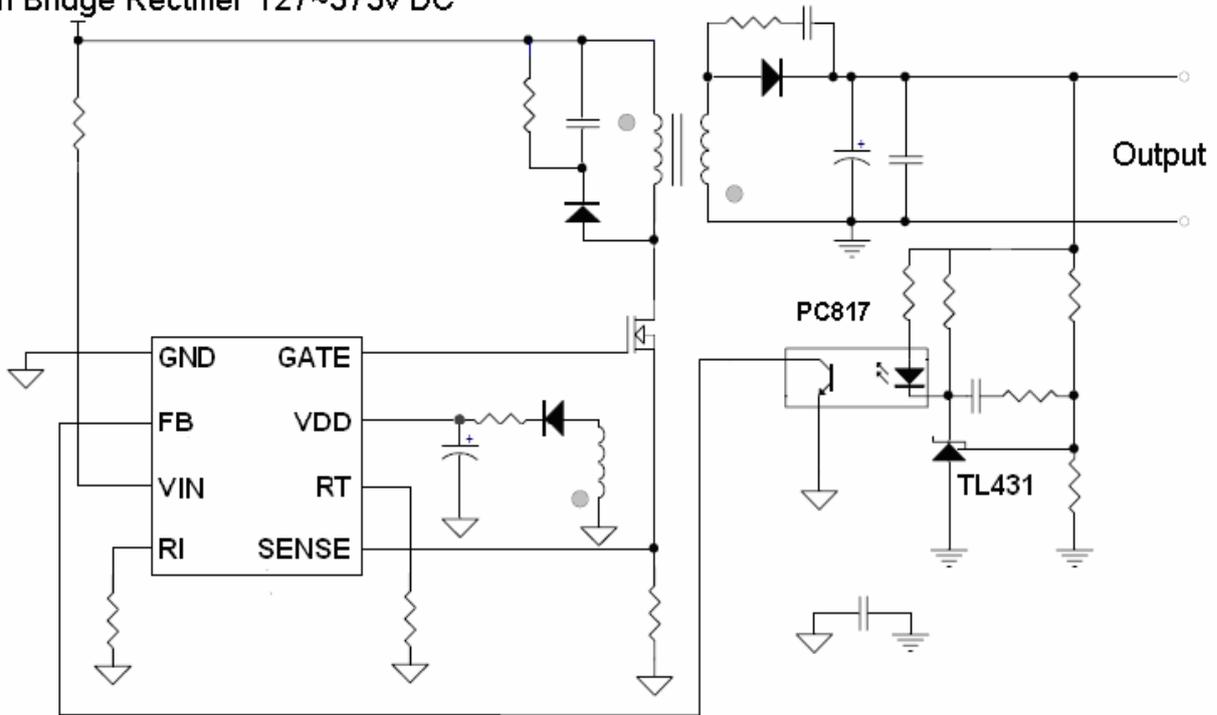


Figure2. Typical Application Circuit of EST2269

Functional Pin Description

Pin Name	Pin Function
GND	Ground
FB	Feedback input pin. The PWM duty cycle is determined by voltage level into this pin and the current-sense signal at Pin sense.
VIN	Star up supply and line sense Pin
RI	Internal Oscillator frequency setting pin. A resistor connected between RI and GND sets the PWM frequency.

RT	OTP sense pin, connect a NTC resistor to GND.
SENSE	Current sense input pin. Connected to MOSFET current sensing resistor node.
VDD	Chip DC power supply pin.
GATE	Totem-pole gate drive output for the power MOSFET.

Block Diagram

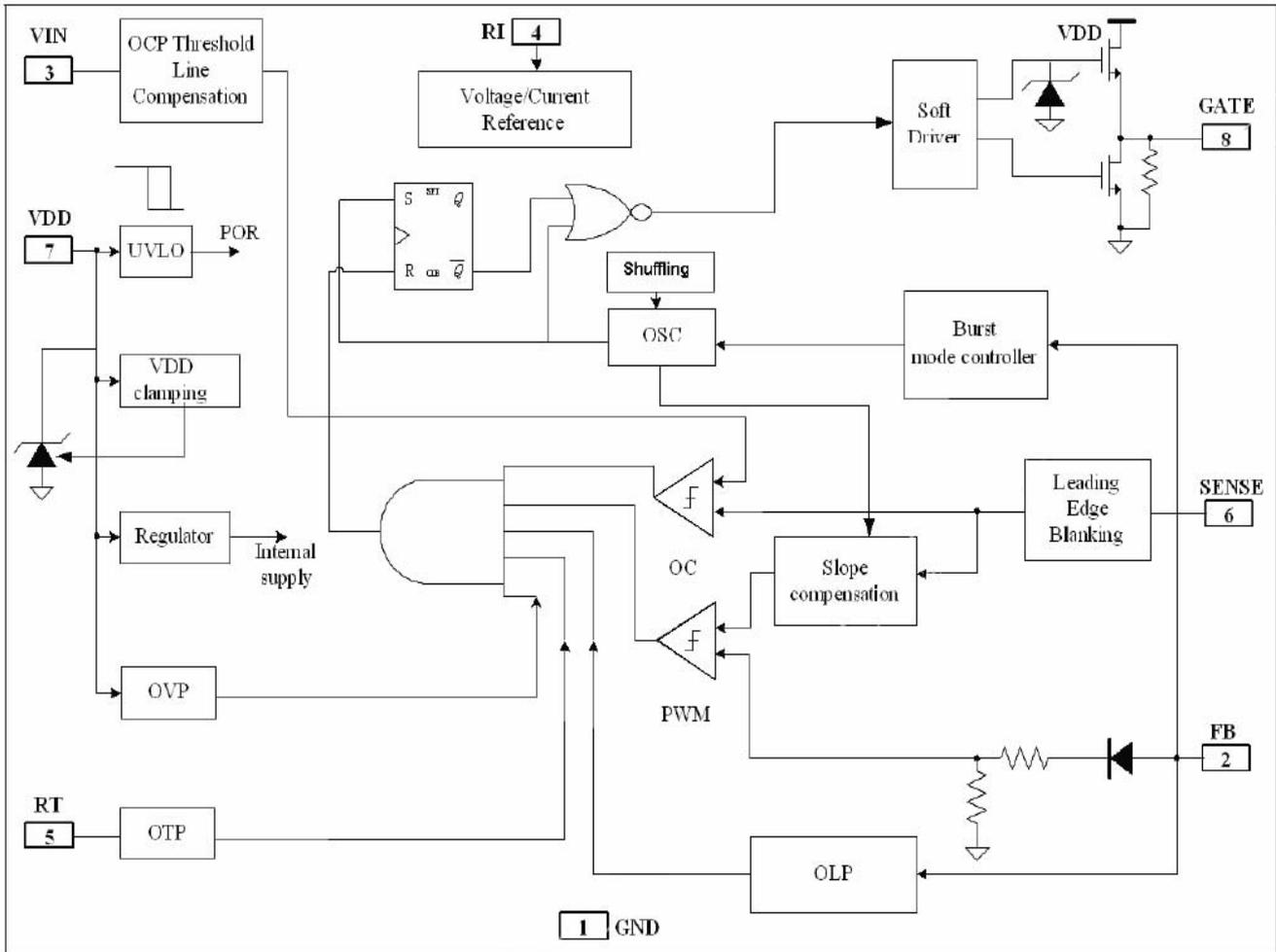


Figure 3. Block Diagram of EST2269

Absolute Maximum Ratings

■ VDD/VIN to GND-----	+ 30V
■ VDD zener clamp voltage-----	VDDclamp+0.1 KΩ
■ VDD clamped current-----	10mA
■ VFB, VSENSE ,VRT and VRI to GND-----	- 0.3V to + 7V
■ Junction Temperature-----	- 20°C to + 85°C
■ Storage Temperature Range-----	- 55°C to + 160°C

Note: Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device.

Recommended Operating Conditions

■ Supply Voltage, VDD-----	12V to + 23V
■ RI resistor value-----	24kOhm
■ Operation Temperature Range-----	- 20°C to + 85°C

ESD In formations

■ Human Body Mode-----	2000V
■ Machine Mode-----	200V

Electrical Characteristics

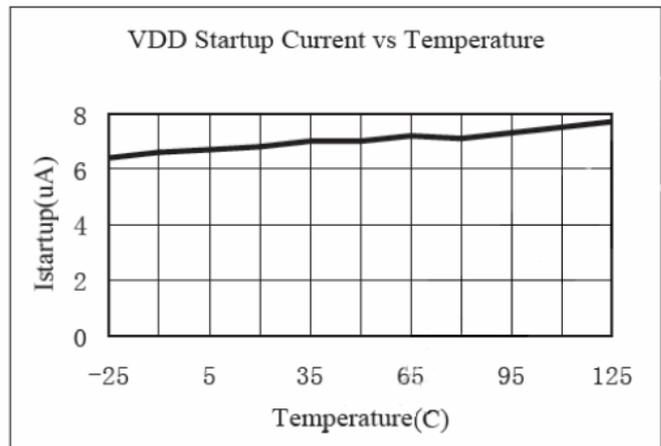
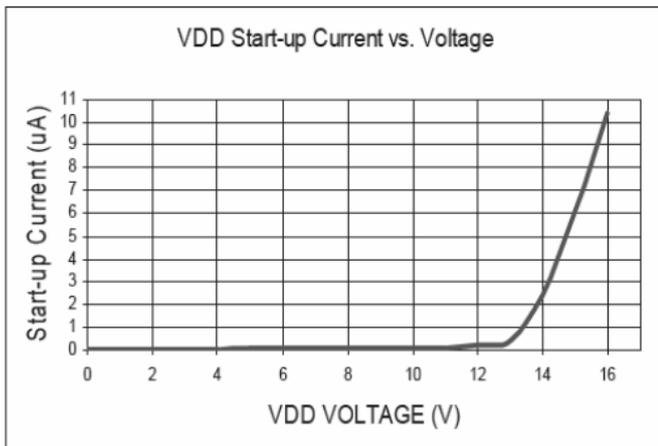
(TA = 25°C, RI=24kOhm, VDD=16V if not otherwise noted)

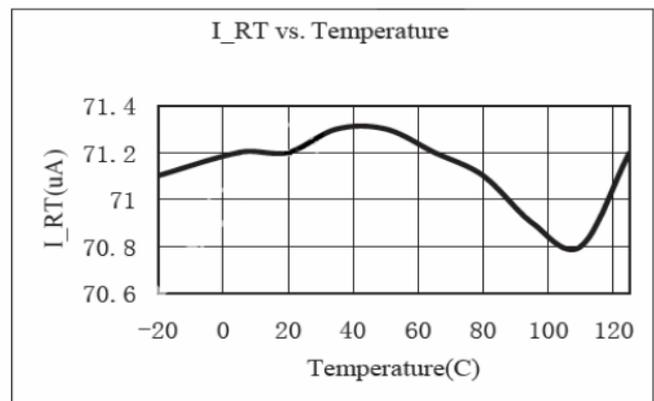
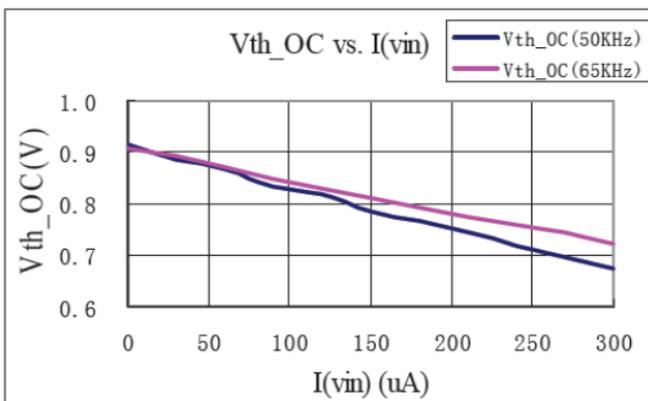
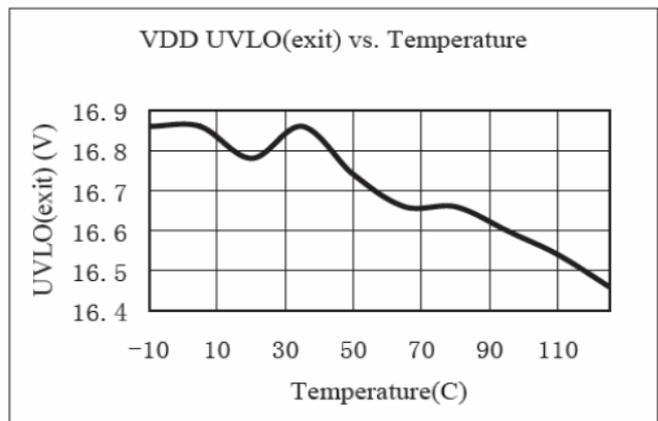
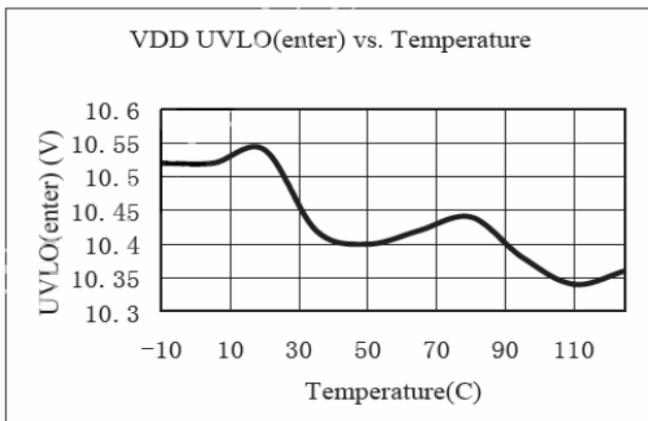
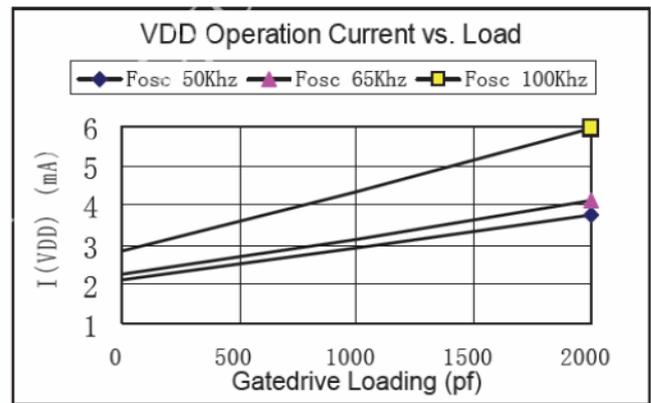
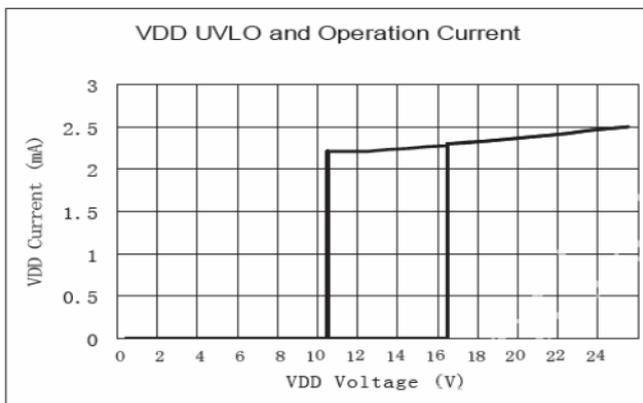
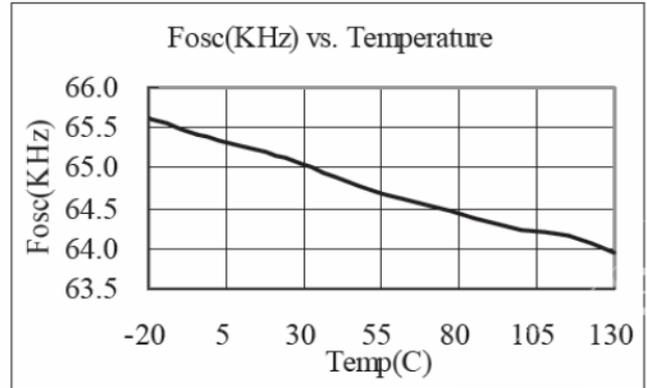
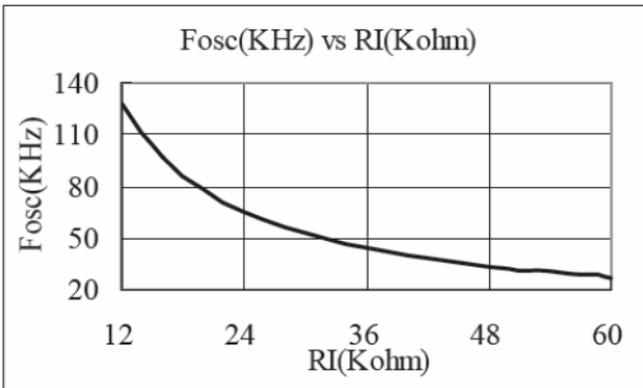
Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
SUPPLY SECTION						
Chip start up current via VDD pin	I_set	Vdd=15V, measure current into VDD pin		3	10	uA
Operation current	I_op	VDD=16V,VFB=3V		2.3		mA
VDD UVLO enter	UVLO_L		9.5	10.5	11.5	V
VDD UVLO exit	UVLO_H		15.5	16.5	17.5	V
VDD clamp voltage	VDD_CLP	I(VDD)=10mA		30		V
OVP enter	OVP_ON		25	27	29	V
OVP hysteresis	OVP_Hys	OVP_ON-OVP_OFF		2		V
OVP debounce time	TD_OVP			80		uS
FEEDBACK SECTION						
PWM input gain	A_PWM	$\Delta VFB/\Delta VCS$		2.8		V
VFB open loop voltage	VFB_O			5.3		
FB pin short circuit current	VFB_S	Short FB pin to gnd and measure current		0.9		mA
Burst mode FB threshold	VFB_th_BM			1.5		V
Power limiting FB threshold	VFB_th_P	Iout= -10mA		4.4		V
Power limiting delay time	T_PL_D			64		mA
OSCILLATOR						
Normal oscillation frequency	Fosc			65		KHz
Frequency temperature stability	Δf_Temp	TA -20°C to +100°C		2		%
Frequency supply stability	Δf_Sup	VDD 12-25V		2		%

Operating RI range	RI_range		12	24	60	KΩ
RI open load voltage	RI_open			2		V
Burst mode base frequency	Fosc-BM			22		KHz
Frequency modulate range (jitter)	Δf_osc		-3		3	%
Maxim duty cycle	D_MAX	VDD=18V,FB=3V,SENSE=0V		80		%
Minimal duty cycle	D_MIN			0		%
Leading edge blanking time	T_blank			250	300	nS
Sense pin input impedance	R_sense			30		kΩ
Over current threshold voltage while no compensation	VTH_OC_0	I(VIN)=0uA	0.85	0.90	0.95	V
Over current threshold voltage while compensation	VTH_OC_1	I(VIN)=150uA		0.81		V
GATE OUTPUT						
Output low level	VOL	VDD=18V,Io=-20mA			0.3	V
Output high level	VOH	VDD=18V,Io=-20mA	11V			V
Output voltage clamped level	VG_CLP			18		V
Output rising time	T_r	VDD=18V,Ci=1nf		110		nS
Output falling time	T_f	VDD=18V,Ci=1nf		40		nS
OVER TEMPERATURE PROTECTION						
Output current of RT pin	I_RT			70		uA
OTP threshold voltage	VTH_OTP		0.9	1.05	1.15	V
OTP recovery voltage	VTH_OTP_off			1.15		V
OTP debounce time	TD_OTP			100		uS

Characterization Plots

VDD = 16V, RI = 24 Kohm, TA = 25oC condition applies if not otherwise noted





Application Information

The EST2269 is a highly integrated PWM controller IC optimized for offline flyback converter applications. The extended burst mode control greatly reduces the standby power consumption and helps the design easily meet the international power conservation requirements.

Startup Current and Start up Control

Startup current of EST2269 is designed to be very low so that VDD could be charged up above UVLO(exit) threshold level and device starts up quickly. A large value startup resistor can therefore be used to minimize the power loss yet reliable startup in application. For a typical AC/DC adaptor with universal input range design, a 2 MΩ, 1/8 W startup resistor could be used together with a VDD capacitor to provide a fast startup and yet low power dissipation design solution.

Operating Current

The Operating current of EST2269 is low at 2.3mA. Good efficiency is achieved with EST2269 low operating current together with extended burst mode control schemes.

Frequency shuffling for EMI improvement

The frequency Shuffling/jittering (switching frequency modulation) is implemented in EST2269. The oscillation frequency is modulated with a internally generated random source so that the tone energy is evenly spread out. The spread spectrum minimizes the conduction band EMI and therefore eases the system design in meeting stringent EMI requirement.

Burst Mode Operation

At zero load or light load condition, most of the power dissipation in a switching mode power supply is from switching loss on the MOSFET transistor, the core loss of the transformer and the loss on the snubber circuit. The magnitude of power loss is in proportion to the number of switching events within a fixed period of time. Reducing switching events leads to the reduction on the power loss and thus conserves the energy.

EST2269 self adjusts the switching mode according to the loading condition. At from no load to light/medium load condition, the FB input drops below burst mode threshold level (1.8V). Device enters Burst Mode control. The Gate drive output switches only when VDD voltage drops below a preset level and FB input is active to output an on state. Otherwise the gate drive remains at off state to minimize the switching loss thus reduce the standby power consumption to the greatest extent. The nature of high frequency switching also reduces the audio noise at any loading conditions.

Oscillator Operation

A resistor connected between RI and GND sets the constant current source to charge/discharge the internal cap and thus the PWM oscillator frequency is determined. The relationship between RI and switching frequency follows the below equation within the specified RI in Kohm range at nominal loading operational condition.

$$F_{osc} = 1560/RI(K\Omega) (Khz)$$

Current Sensing and Leading Edge Blanking

Cycle-by-Cycle current limiting is offered in EST2269 current mode PWM control. The switch current is detected by a sense resistor into the sense pin. An internal leading edge blanking circuit chops off the sense voltage spike at initial MOSFET on state due to snubber diode reverse recovery so that the external RC filtering on sense input is no longer required. The current limit comparator is disabled and thus cannot turn off the external MOSFET during the blanking period. PWM duty cycle is determined by the current sense input

voltage and the FB input voltage.

Internal Synchronized Slope Compensation

Built-in slope compensation circuit adds voltage ramp onto the current sense input voltage for PWM generation. This greatly improves the close loop stability at CCM and prevents the sub-harmonic oscillation and thus reduces the output ripple voltage.

Over Temperature Protection

A NTC resistor in series with a regular resistor should connect between RT and GND for temperature sensing and protection. NTC resistor value becomes lower when the ambient temperature rises. With the fixed internal current IRT flowing through the resistors, the voltage at RT pin becomes lower at high temperature. The internal OTP circuit is triggered and shutdown the MOSFET when the sensed input voltage is lower than VTH_OTP.

Gate Drive

EST2269 Gate is connected to the Gate of an external MOSFET for power switch control. Too weak the gate drive strength results in higher conduction and switch loss of MOSFET while too strong gate drive output compromises the EMI.

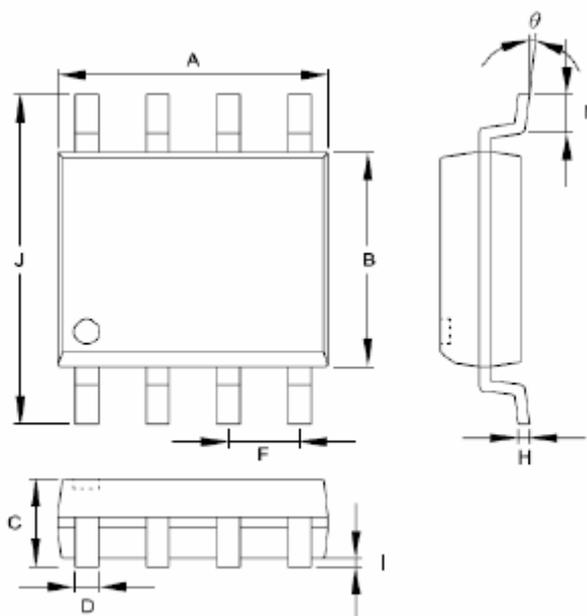
Good tradeoff is achieved through the built-in totem pole gate drive design with right output strength and dead time control. The low idle loss and good EMI system design is easier to achieve with this dedicated control scheme. An internal 18V clamp is added for MOSFET gate protection at higher than expected VDD input.

Protection Controls

Good system reliability is achieved with EST2269's rich protection features including Cycle-by- Cycle current limiting (OCP), Over Load Protection (OLP), over temperature protection (OTP), on chip VDD over voltage protection (OVP, optional) and under voltage lockout (UVLO).

The OCP threshold value is self adjusted lower at higher current into VIN pin. This OCP threshold slope adjustment helps to compensate the increased output power limit at higher AC voltage caused by inherent Over-Current sensing and control delay. A constant output power limit is achieved with recommended OCP compensation scheme on EST2269. At output overload condition, FB voltage is biased higher. When FB input exceeds power limit threshold value for more than 80mS, control circuit reacts to turnoff the power MOSFET. Similarly, control circuit shutdowns the power MOSFET when an Over Temperature condition is

Package Information



SOP-8

Symbols	Dimensions in Millimeters		Dimensions in Inch	
	MIN	MAX	MIN	MAX
A	4.801	5.004	0.189	0.197
B	3.810	3.988	0.150	0.157
C	1.346	1.753	0.053	0.069
D	0.330	0.508	0.013	0.020
F	1.194	1.346	0.047	0.053
H	0.178	0.229	0.007	0.009
I	0.102	0.254	0.004	0.010
J	5.791	6.198	0.228	0.244
M	0.406	1.270	0.016	0.050
θ	0°	8°	0°	8°